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Simulation and Progress in Ionization Profile Monitors for High Intensity Proton Beam

Kenichirou Satou J-PARC/KEK

Outline

- Introduction
 - What is IPM?
 - Particle detection
 - J-PARC system
- Two mode operations
 - Ion collection mode, w.o. magnetic guiding field
 - Electron motion in electric and magnetic guiding field
- New simulation code of IPM, IPMsim3D
- Recent progresses of IPM
 - New IPM for the CERN-PS
 - Gated IPM system in FNAL
- IPM workshop
- Summary

What is IPM ?

- Ionization Profile Monitor (IPM)
- Non-destructive 1D profile monitor
- 1D profile monitor based on the **beam induced ionizations**
- Charged particle produced by the ionization
 - Residual gas, gas inlet (Supersonic gas jet, gas chamber)
 - Charged particle detection, Gas fluorescence
- Two mode operations: Ion w.o. Bg or electron w Bg
 - Low intensity and DC beam : Ion collection mode
 - High intensity bunched beam : E collection mode
- There are long history, since 1966, however it is hard to say that this is a well established technique because of its complexity on particle motion and contamination issue
 - The first IPM
 - V. Dudnikov, "The intense proton beam accumulation in storage ring by charge-exchange injection method", Ph.D. Thesis, Novosibirsk INP, 1966.
 - G. Budker, G. Dimov, and V. Dudnikov, in proceedings of the international symposiumon electron and positron storage rings, Saclay, France, 1966 (Saclay, Paris, 1966), Article No. VIII-6-1.

Particle detections



Signal estimate in case of J-PARC MR

Beam intensity, Nb: 4E11~13 ppb Proton Energy: 3-30 GeV Pressure, P: 5E-7 Pa Gas: Hydrogen Stopping power, dE/dx : 4.3 MeV cm²/g W value: 36 eV Density, ρ : 8.99E-5 g/cm³/atm I. Detector size, dZ: 2 cm

Number of ion-electron pairs : N $N = N_b \rho \frac{P}{10^5} \frac{dE}{dx} \frac{1}{W} dZ = 43 \sim 4300 \text{ per bunch}$

Signal multiplier is basically needed

- Rectangular MCP with multi-anode
- Rectangular MCP with phosfer screen



Local gain change for long time usage

Calibration method is required

•Beam based, Thin wire, EGA, EV light

Channeltron system (ISIS/RAL IPM) Courtesy by Mr. Wilcox



A single channeltron



The 40 channeltron array used to measure beam profile



Profile measured by the multi-channeltron detector

Gain calibration can be made using movable single channeltron detector

-6 mm

Longitudinal electric potential distribution created by the two drift field electrodes

MCPM

J-PARC IPM: Components and two mode operations

- A set of electrodes to generate electric field to collect charged particle
- High voltage to collect charged particle against a strong space charge electric field of the high intensity bunched beam
 - Space charge E field
 - 2MV/m for MR ext. beam
- 3-pole magnet system to generate guiding field to collect electrons against space charge electric field

Ideally the E and B field doesn't make any force

- MCP to multiply the signal
- Multi strip anode to read out the charge from MCP
- Electron source, EGA (Electron generator arrays), to check gain aging of the MCP -> Will be removed this summer





Photo of IPM

Turn by turn profile measurements Ion collection, Inj. beam

From 1st turn to 14th turn profile measured at J-PARC IPM



Injection miss-match Q mode + D mode After Q mode tuning D mode After Q and D mode tuning

Ion collection without B?

Beam parameters of J-PARC MR • Injection (3 GeV) σ_t =40ns(600ns interval), σ_x =7.6mm, σ_y =12.3mm • Extraction (30 GeV) σ_t = 10ns(588ns interval), σ_x = 2.7mm, σ_y = 4.4mm

Calculated space charge E field is Potential_max=47kV, Es_max≈2MV/m required HV to overcome the Es is, 2MV/m*130mm=260kV!!

Even if we can apply the 260 kV DC between the electrodes (130mm gap), the profile will be,,,,

Profile: ion w.o. B, 260 kV



Ion collection w.o. B

Model based reconstruction method can

If the beam intensity is 1/10, the profile will be,,,



Electron collection mode w. Bg: IPM for high intensity proton accelerators

Electron motion acting with Ec, Es, and Bg Position resolution estimate for simple case, const. fields.

Electron motion in E(=const.) and B(=const.) field

Equation of motion



Integration should be made along the trajectory, the fields depend on positions, so the pass integral can not be analytically obtained. -> const. fields are assumed here



Why we need strong B?

 $\underbrace{i}_{\omega} \widetilde{v_0} (e^{-i\omega t} - 1) + \underbrace{\tilde{E}}_{B} \{\frac{1}{\omega} (e^{-i\omega t} - 1) + it\} + i \underbrace{\frac{E_y}{B}}_{B} \widetilde{\theta} \{\frac{1}{\omega} (e^{-i\omega t} - 1) + it\} - \frac{1}{2} \frac{eE_y}{m} t^2 (\approx FL) \widetilde{\theta}$

 $\Delta x \text{ by Initial velocity term (Larmore rotation):}$ $\Delta x = \frac{v_0}{\omega} = \frac{mv_0}{eB} = \frac{10^{-5}}{B} \text{ [m]} \text{ In case of TKE=10eV}$ $\Delta x \text{ by Error field, } E_{sx} \text{ (Larmore rotation):}$ $\Delta x = 2 \frac{\alpha}{\omega} = 2 \frac{E_{sx}/B}{\omega} = \frac{E_{sx}m}{eB^2} = \frac{0.5 \times 10^{-10}}{B^2} E_{sx} \text{ [m]}$ $\Delta x \text{ by Error field, } E_{cz}, E \times B \text{ drift:}$ $\Delta x = \frac{E_{cz}}{B} \times TOF = 10^{-9} \frac{E_{cz}}{B} \text{ In case of TOF=1 ns}$



These fields depend on the cage and magnet design and Es is depend on the beam profile \Rightarrow 3D simulation code

Is it possible to collect electrons only from the ionization process?: Contamination issue



- The turn by turn profile showed beam induced contamination, and it depends on Ec, Bg fields as well as beam parameters
- The contaminant electrons appeared ~1.5 μs after the beam passage
- Mechanism of this contamination issue is now under investigation
- Simulation not only for electrons gene. in the cage but also electrons gene. outside of the cage

Python based 3D particle tracking code Profile simulator for IPM design: IPMsim3D



Flow chart of the simulator

Electron trajectory in strong Es



An example of calculated profile



Profile, B=0.2T

Existing simulation codes for IPM

Name/Lab	Language	Ionization	Guiding	shana	Beam	Tracking
			liciu	snape	lield	
GSI code	C++	simple	uniform	parabolic	3D analytic	numeric
		DDCS	E,B	3D	relativ.	R-K 4 th order
PyECLOUD-BGI	python	realistic	uniform	Gauss	2D analytic	analytic
/CERN		DDCS	E,B	3D	relativ. only	
FNAL	MATLAB	simple	3D map	arbitrary	3D numeric	num. MATLAB
		SDCS	E,B		relativ. (E and B)	rel. eq. of motion
ISIS	C++	at rest	CST map	arbitrary	2D numeric (CST)	numeric
			E only	(CST)	non-relativ.	Euler 2nd order
IFMIF	C++	at rest	Lorenz-3E map	General.	numeric (Lorenz-3E)	
			E only	Gauss	non-relativ.	
ESS	MATLAB	at rest	uniform	Gauss	3D numeric (MATLAB)	numeric
			E,B	3D	relativ.	MATLAB R-K
IPMSim3D	python	realistic	2D/3Dmap	Gauss	2D numeric (SOR)	numeric
/J-PARC		DDCS	E, B	3D	relativ. only	R-K 4 th order

Table 1: The Current Simulation Codes. See Text for the Details.

From Proc. of IBIC16, TUPG71, M.Sapinski et. al.

Courtesy of Dr. M.Sapinski (GSI)

New IPM simulation code by D. Vilsmeier, P. Forck and M. Sapinski (GSI) Poster presentation: WEPCC07 New modules are added: Beam gas interactions -> Beam Induced Fluorescence Monitors (BIF) simulation

Cross checking



New GSI code vs. IPMsim3D Courtesy of Mr. D. Vilsmeier (GSI)

Recent progresses of IPM

CERN PS IPMGated IPM system(FNAL)

New IPM for CERN PS

- Simple cage design
 - Field estimate using CST
 - Optimized by using the IPMsim3D code
- Ion trap
 - Suppress electron contamination originating from ion collision on a electrode
- Multi-pixel Si detector system
 - 55 μm × 55 μm silicon sensor pixels (65,536 pixels)
 - Fast responce
 - Good position resolution
- Oral presentation: WE2AB5, J.W.Story et. al.



Courtesy by Dr. J.W. Storey (CERN)

CERN PS IPM//Ion trap Suppress secondary electron contamination



Simple solution



a)lon motion

1)Accelerate to the cathode

2)Pass through the slot

3)Stop at the point between the slot and the chamber wall

4) Accelerate again to the cathode and captured on the cathode

- b)Secondary electron motion
 - 1)The ion bombardment results in secondary electrons
 - 2)Escaped electrons from the wall goes to the chamber wall

3) And finally these are completely captured

Gated IPM system (FNAL)

- Issue on a charged particle detector, Micro Channel Plate (MCP)
- Local gain degradation after the longterm operation of 9 years, in case of J-PARC MR IPM
 - MCP is used as a charged particle detection and signal amplification devise and its gain uniformity is essential for the profile measurement
 - The local gain decrease with increase the integrated output charge, and thus it is severe at the center area
 - MCP devise is expensive and cannot be replaced easily



Photo of the detector, MCP



Solution: HV DC -> Pulse mode operation





Courtesy of James R Zagel: Photo and block diagram of the HV switching module for FANL IPM





Courtesy of Randy Thurman-Keup (FNAL), profile measured by the IPM @ FNAL with pulsed HV: From the presentation file of US/Japan monitor meeting at FNAL, 2015.

When 100Hz 1% duty switching operation is used

 $(D_{IPM}: 1 \rightarrow 0.01)$, only 20 turn profiles will be selected for each pulse. MCP life will be extended to 100 times longer than that in the case of non-gated system.

IPM workshop

- The intercommunication framework, IPM workshop, was established.
- First workshop at CERN
 - 3-4 March 2016
 - During the last 40 years numerous codes were written to address various aspects of the electron/ion transport in IPMs, however none of these codes is publicly available, maintained, well documented nor completed.
 - In this workshop an inter-laboratory collaboration with goal to create, benchmark and maintain such a code will be discussed and planned.
 - https://indico.cern.ch/event/491615/
- Second workshop at GSI (ARIES)
 - 21-24 May 2017
 - To share the experience in design and operation of Ionization Profile Monitors
 - Benchmarking and discussion about the IPM codes
 - http://indico.gsi.de/event/5366/



Group photo: First IPM workshop



Group photo: Second IPM workshop

Present issues: We are interested in,,,

From discussions at 2nd IPM workshop

- Light reflection issue in optical IPMs: Experience, cures, coating
- Gas dynamics-Thermal effects
- MCP/Phosphor : aging effect and gain decrease
- How to setup optimal gains in MCP-Phosphor-Camera system?
- How to estimate ionization process?
- Cross checking of the simulation codes, reproducibility check with measured data
- Profile reconstruction problem : Model based, Neural network, CEA method,,,,
- Alternative to MCP? Silicon pixel detector
- Rf-shielding : Rf noise shield, Rf heating problem
- Electron contamination issues

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Plan!!
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Next 3rd IPM workshop: J-PARC, Japan

kenichirou.satou@j-parc.jp

Summary

- Residual gas IPM is a non-destructive profile monitor which can be applied for the high intensity proton accelerator
- However, detector system, calibration system, electron contamination issues are still of utmost concern
- Some of the simulation codes are now available, and some codes are now being cross-checking : IPMsim3D(J-PARC,CERN), ESS code, GSI code, PyEcloud based code (CERN)
- Recent progress was presented
 - CERN PS IPM: Ion trap, Si multi pixel detector (Timepix 3)
 - Gated IPM system
 - Ion trap and gated IPM system for J-PARC is now designing
- IPM workshop is being opened since 2016, as an inter communication frame for IPM researcher (designer)
 - 3rd workshop will go to J-PARC/Japan, 2018 (plan)
 - kenichirou.satou@j-parc.jp
- Presentations on IPM in this conference
 - Oral: WE2AB5: J.W.Story *et.al.*: "First results from the operation of a rest gas ionization profile monitor based on a hybrid pixel detector
 - Poster:WEPCC06: R. Singh *et.al.*: "Simulation supported profile reconstruction with machine learning"
 - Poster: WEPCC07: D.M.Vilsmeier: "A modular application for IPM simulations"
 - Poster: WEPCC13: J. He et. al. : "Preliminary study on ionization profile monitor for ADS injector I"